Datasheet

SiC Schottky Barrier Diode

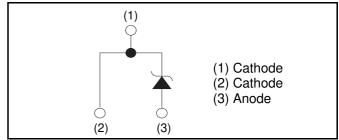
V_R	1200V
I _F	10A
Q_C	34nC

Outline TO-220AC

Features

- 1) Shorter recovery time
- 2) Reduced temperature dependence
- 3) High-speed switching possible

●Inner circuit



Applications

- PFC Boost Topology
- Secondary Side Rectification
- Data Center
- PV Power Conditioners

Packaging specifications

	ging openioune	
	Packaging	Tube
	Reel size (mm)	-
Type	Tape width (mm)	-
Туре	Basic ordering unit (pcs)	50
	Packing code	С
	Marking	SCS210KG

• Absolute maximum ratings $(T_i = 25^{\circ}C)$

Parameter		Symbol	Value	Unit
Reverse voltage (repetitive peak)		V_{RM}	1200	V
Reverse voltage (DC)		V_{R}	1200	V
Continuous forward	d current (T _c = 146°C)	I _F	10	А
Surge non-	PW=10ms sinusoidal, T _j =25°C		42	А
repetitive forward current	PW=10ms sinusoidal, T _j =150°C	I_{FSM}	31	А
	PW=10μs square, T _j =25°C		160	А
Repetitive peak forward current		I _{FRM}	50 ^{*1}	А
PW=10ms, T _j =25°C		ſ.2	9.0	A ² s
i ² t value	PW=10ms, T _j =150°C	$\int i^2 dt$	4.8	A ² s
Total power dissipation		P_D	150 ^{*2}	W
Junction temperature		T _j	175	°C
Range of storage temperature		T _{stg}	-55 to +175	°C

^{*1} T_c=100°C, T_i=150°C, Duty cycle=10% *2 T_c=25°C

•Electrical characteristics $(T_j = 25^{\circ}C)$

Parameter	Symbol	Conditions	Values			Unit
			Min.	Тур.	Max.	Unit
DC blocking voltage	V_{DC}	I _R =0.2mA	1200	-	-	V
	V _F	I _F =10A,T _j =25°C	-	1.4	1.6	V
Forward voltage		I _F =10A,T _j =150°C	-	1.8	-	V
		I _F =10A,T _j =175°C	-	1.9	-	V
Reverse current	I _R	V _R =1200V,T _j =25°C	-	10	200	μΑ
		V _R =1200V,T _j =150°C	-	80	-	μΑ
		V _R =1200V,T _j =175°C	-	130	-	μΑ
Total capacitance	С	V _R =1V,f=1MHz	-	530	-	рF
		V _R =800V,f=1MHz	-	43	-	pF
Total capacitive charge	Q _C	V _R =800V,di/dt=500A/μs	-	34	-	nC
Switching time	t _C	V _R =800V,di/dt=500A/μs	-	15	-	ns

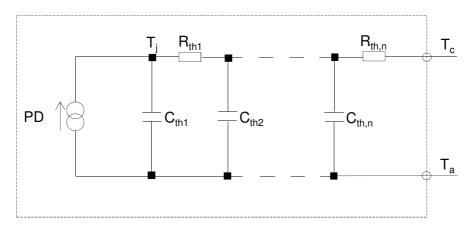
Thermal characteristics

Parameter	Symbol	Conditions	Values			Unit
			Min.	Тур.	Max.	Offic
Thermal resistance	$R_{\text{th(j-c)}}$	-	-	0.73	0.99	°C/W

● Typical Transient Thermal Characteristics

Symbol	Value	Unit
R _{th1}	1.92E-01	
R _{th2}	5.39E-01	K/W
R _{th3}	3.91E-05	

Symbol	Value	Unit
C_{th1}	3.18E-03	
C_{th2}	6.56E-03	Ws/K
C_{th3}	1.40E+02	



•Electrical characteristic curves

Fig.1 V_F - I_F Characteristics

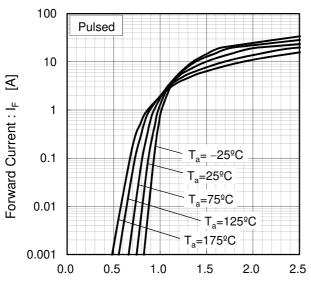
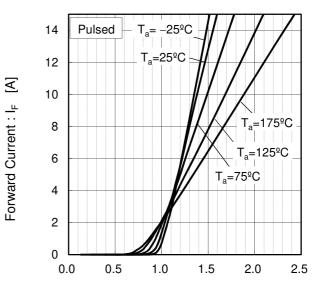


Fig.2 V_F - I_F Characteristics



Forward Voltage : V_F [V] Forward Voltage : V_F [V]

Fig.3 V_R - I_R Characteristics

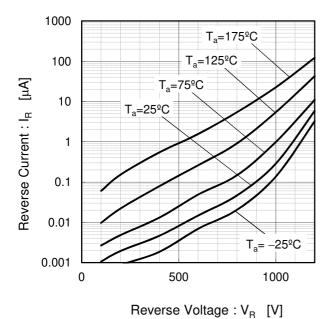
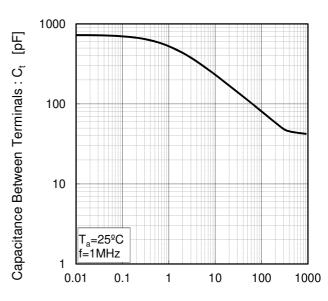


Fig.4 V_R - C_t Characteristics



Reverse Voltage: V_R [V]

Electrical characteristic curves

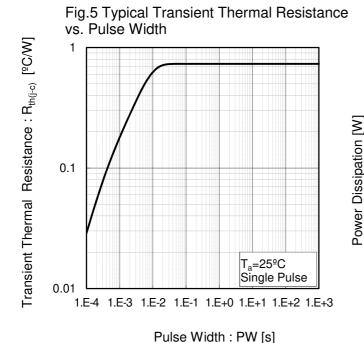
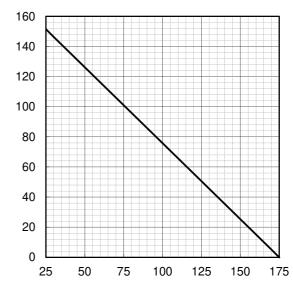


Fig.6 Power Dissipation



Case Temperature : T_c [ºC]

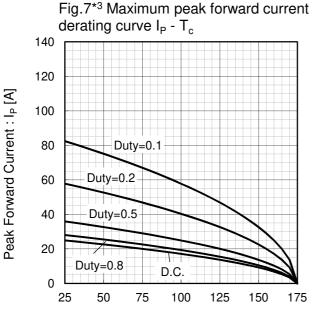
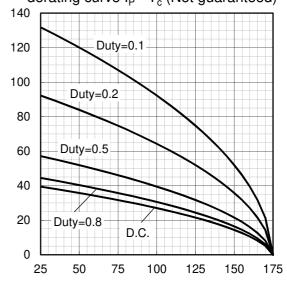


Fig.8*4 Typical peak forward current derating curve I_P - T_c (Not guaranteed)

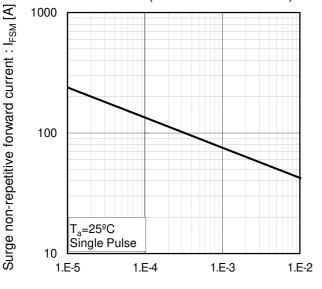


Case Temperature : T_c [^oC]
*4 Based on typ Vf, typ R_{th(j-c)}
Typical value, not guaranteed
Valid for switching of above 10kHz,
excluding D.C. curve

Peak Forward Current : I_P [A]

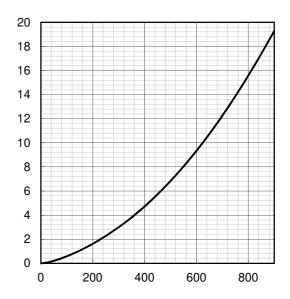
•Electrical characteristic curves

Fig.9 Surge non-repetitive forward current vs. Pulse width (Sinusoidal waveform)



Pulse Width : PW [s]

Fig.10 Typical capacitance store energy

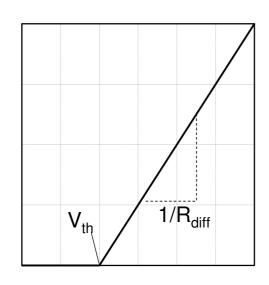


Capacitance stored energy ։ $\mathsf{E}_{\mathrm{C}}[\mu J]$

Reverse Voltage: V_R [V]

Symplified forward characteristic model

Fig.11 Equivalent forward current curve



Forward Voltage: V_F

$$V_F = V_{th} + R_{diff} I_F$$

$$\begin{aligned} &V_{th} \left(\ T_{j} \ \right) = a_{0} + a_{1} \, T_{j} \\ &R_{diff} \left(\ T_{j} \ \right) = b_{0} + b_{1} \, T_{j} + b_{2} \, T_{j}^{2} \end{aligned}$$

Symbol	Typical Value	Unit
a ₀	9.93E-01	V
a ₁	-1.27E-03	V/°C
b ₀	3.65E-02	Ω
b ₁	2.06E-04	Ω/°C
b ₂	1.33E-06	Ω/°C ²

 $T_i \text{ in } {}^{\circ}\text{C}; -55 {}^{\circ}\text{C} < T_i < {}^{\circ}\text{C} ; I_F < 20 \text{ A}$

Forward Current : IF

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